

IRFB17N20D

Request a Quote

IRFB17N20D Information

	www.elspeer.com	Part Number	IRFB17N20D	
		Manufacturer	Infineon Technologies	
4 ww		Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
		Description	MOSFET N-CH 200V 16A TO-220AB	
		Package	TO-220-3	
			For the pricing/inventory/lead time, please contact us	
For	Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFB17N20D Specifications

Manufacturer Part Number	IRFB17N20D
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	16A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1100pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	3.8W (Ta), 140W (Tc)
Rds On (Max) @ Id, Vgs	170 mOhm @ 9.8A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRFB17N20D Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFB17N20D Payment Methods



IRFB17N20D Shipping Methods



If you have any question about IRFB17N20D, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com